








	<h2>SI3445ADV-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI3445ADV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 8V 4.4A 6-TSOP</p> <p>Datenblätter:  SI3445ADV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 23585 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3445ADV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 8V 4.4A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	23585 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.1W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.4A (Ta)
Rds On (Max) @ Id, Vgs	42 mOhm @ 5.8A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI3445ADV-T1-GE3 ist neu im Original, Suche SI3445ADV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3445ADV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3445ADV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI3445DV VISHAY SI3445DV VISHAY	 SI3445DV-T1-E3 Vishay / Siliconix MOSFET P-CH 8V 6-TSOP	 SI3445ADV-T1-E3 Vishay / Siliconix MOSFET P-CH 8V 4.4A 6-TSOP	 SI3445ADV VISHAY VISHAY SOT-163SO
 SI3445ADV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 4.4A 6-TSOP	 SI3445DV-NL FAIRCHILD FAIRCHILD TSOP-6	 SI3445DV-T1 VISHAY SI3445DV-T1 VISHAY	 SI3445BDV VISHAY SI3445BDV VISHAY

heiße Teile

Mehr

 SI3443BDV	 SI3443BDV-T1-E3	 SI3443BDV-T1-E3	 SI3443BDV-T1-GE3	 SI3443BDV-T1-GE3
 SI3443BVD	 SI3443CDV-T1-E3	 SI3443CDV-T1-E3	 SI3443CDV-T1-GE3	 SI3443CDV-T1-GE3
 SI3443DDV-T1-GE3	 SI3443DDV-T1-GE3	 SI3443DV	 SI3443DV	 SI3443DV
 SI3443DV-NL	 SI3443DV-T1	 SI3443DV-T1-E3	 SI3443DV-T1-GE3	 SI3443DVTR
 SI3443DVTRPBF	 SI3445ADV-T1	 SI3445ADV-T1-E3	 SI3445ADV-T1-E3	 SI3445ADV-T1-GE3
 SI3445BDV	 SI3445DV	 SI3445DV-T1	 SI3445DV-T1-E3	 SI3445DV-T1-E3
 SI3445DV-T1-E3	 SI3445DV-T1-GE3	 SI3445DV-T1-GE3	 SI3446ADV-T1	 SI3446ADV-T1-E3
 SI3446ADV-T1-E3	 SI3446ADV-T1-GE3	 SI3446ADV-T1-GE3	 SI3446BDV	 SI3446DV
 SI3446DV-T1	 SI3446DV-T1-E3	 SI3446DV-T1-GE3	 SI3446DV-T1-E3	 SI3447BDS
 SI3447BDV	 SI3447BDV-T1	 SI3447BDV-T1-E3	 SI3447BDV-T1-E3	 SI3447BDV-T1-GE3

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